



CNY17-1, CNY17-2, CNY17-3, CNY17-4 CNY17F-1, CNY17F-2, CNY17F-3, CNY17F-4 DC Input 6-Pin Phototransistor Optocoupler

Features

- High isolation 5000 VRMS
- CTR flexibility available see order information
- DC input with transistor output
- Operating temperature range - 55 °C to 110 °C

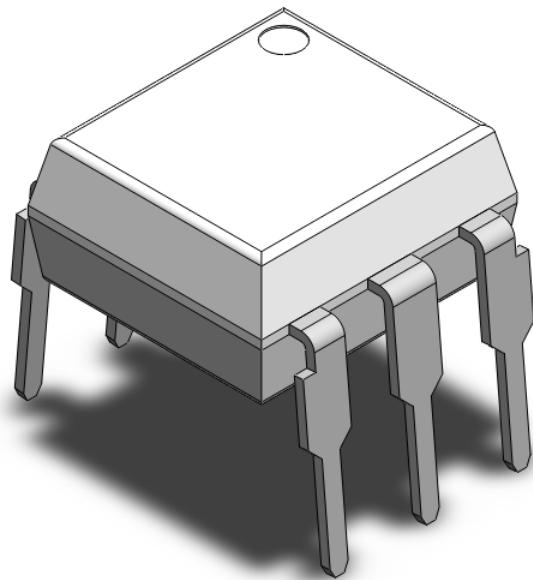
Description

The CNY17 and CNY17F series consists of a photo transistor optically coupled to a gallium arsenide Infrared-emitting diode in a 6-lead DIP package with different lead forming options.

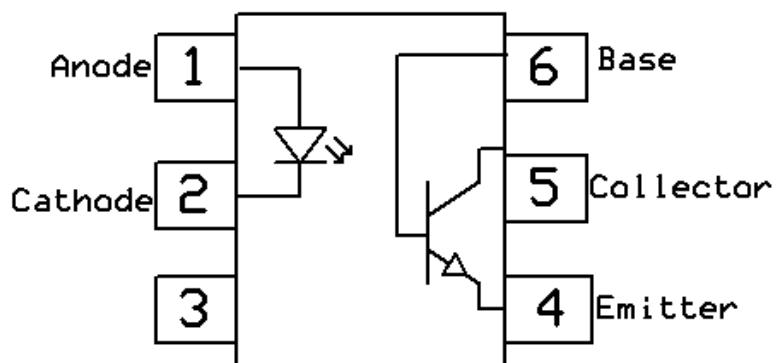
Applications

- Switch mode power supplies
- Computer peripheral interface
- Microprocessor system interface

Package Outline



Schematic



Note: CNY17F without Base Connection

Note: Different lead forming options available. See package dimension.



**CNY17-1, CNY17-2, CNY17-3, CNY17-4
CNY17F-1, CNY17F-2, CNY17F-3, CNY17F-4
DC Input 6-Pin Phototransistor Optocoupler**

Absolute Maximum Rating at 25°C

Symbol	Parameters	Ratings	Units	Notes
V _{ISO}	Isolation voltage	5000	V _{RMS}	
T _{OPR}	Operating temperature	-55 ~ +110	°C	
T _{STG}	Storage temperature	-55 ~ +150	°C	
T _{SOL}	Soldering temperature	260	°C	
Emitter				
I _F	Forward current	60	mA	
I _{F(TRANS)}	Peak transient current (≤1μs P.W,300pps)	1	A	
V _R	Reverse voltage	6	V	
P _D	Power dissipation	100	mW	
Detector				
P _D	Power dissipation	150	mW	
B _{VCEO}	Collector-Emitter Breakdown Voltage	80	V	
B _{VCEO}	Collector-Base Breakdown Voltage	80	V	
B _{VECO}	Emitter-Collector Breakdown Voltage	7	V	
B _{VEBO}	Emitter-Base Breakdown Voltage	7	V	



CNY17-1, CNY17-2, CNY17-3, CNY17-4 CNY17F-1, CNY17F-2, CNY17F-3, CNY17F-4 DC Input 6-Pin Phototransistor Optocoupler

Electrical Characteristics $T_A = 25^\circ\text{C}$ (unless otherwise specified)

Emitter Characteristics

Symbol	Parameters	Test Conditions	Min	Typ	Max	Units	Notes
V_F	Forward voltage	$I_F=10\text{mA}$		1.24	1.4	V	
I_R	Reverse Current	$V_R = 6\text{V}$	-	-	5	μA	
C_{IN}	Input Capacitance	$f= 1\text{MHz}$	-	20	-	pF	

Detector Characteristics

Symbol	Parameters	Test Conditions	Min	Typ	Max	Units	Notes
B_{VCEO}	Collector-Emitter Breakdown	$I_C = 0.1\text{mA}$	80	-	-	V	
B_{VECO}	Emitter-Collector Breakdown	$I_E = 0.1\text{mA}$	7	-	-	V	
B_{VCBO}	Collector-Base Breakdown	$I_C = 0.1\text{mA}$ $I_E = 0.1\text{mA}$	80	-	-	V	
B_{VEBO}	Emitter-Base Breakdown		7	-	-	V	
I_{CEO}	Collector-Emitter Dark Current	$V_{CE} = 10\text{V}, I_F = 0\text{mA}$	-	-	50	nA	
I_{CBO}	Collector-Base Dark Current	$V_{CB} = 10\text{V}, I_F = 0\text{mA}$	-	-	20	nA	

Transfer Characteristics

Symbol	Parameters	Test Conditions	Min	Typ	Max	Units	Notes
CTR	Current Transfer Ratio	$I_F = 10\text{mA}, V_{CE} = 5\text{V}$	40	-	80	%	
			63	-	125		
			100	-	200		
			160	-	320		
	CTR	$I_F = 1\text{mA}, V_{CE} = 5\text{V}$	13	-	-		
			22	-	-		
			34	-	-		
			56	-	-		
$V_{CE(SAT)}$	Collector-Emitter Saturation Voltage	$I_F = 10\text{mA}, I_C = 2.5\text{mA}$	-	-	0.3	V	
R_{IO}	Isolation Resistance	$V_{IO} = 500\text{V}_{\text{DC}}$	1×10^{11}			Ω	
C_{IO}	Isolation Capacitance	$f = 1\text{MHz}$		0.25		pF	



**CNY17-1, CNY17-2, CNY17-3, CNY17-4
CNY17F-1, CNY17F-2, CNY17F-3, CNY17F-4
DC Input 6-Pin Phototransistor Optocoupler**

Switching Characteristics

Symbol	Parameters	Test Conditions	Min	Typ	Max	Units	Notes
T _{ON}	Turn On Time	I _c = 2mA, V _{CE} = 10V, R _L = 100	-	4.3	11.5	μs	
t _r	Rise Time		-	9.8	9.8		
T _{OFF}	Turn Off Time		-	3.9	11.5	μs	
t _f	Fall Time		-	6.9	9.8		



CNY17-1, CNY17-2, CNY17-3, CNY17-4 CNY17F-1, CNY17F-2, CNY17F-3, CNY17F-4 DC Input 6-Pin Phototransistor Optocoupler

Typical Characteristic Curves

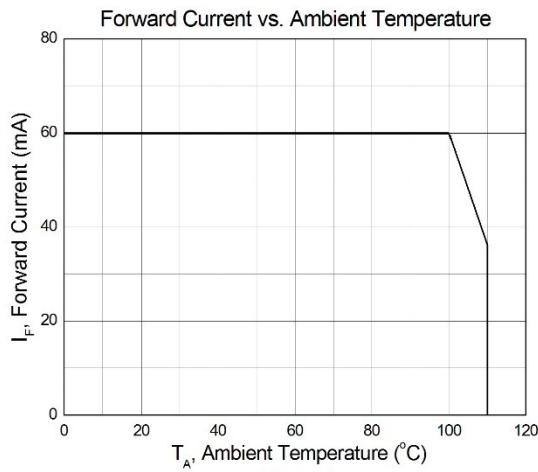


Figure 1

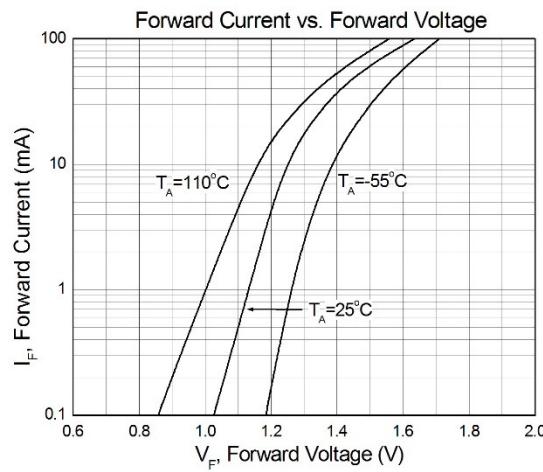


Figure 2

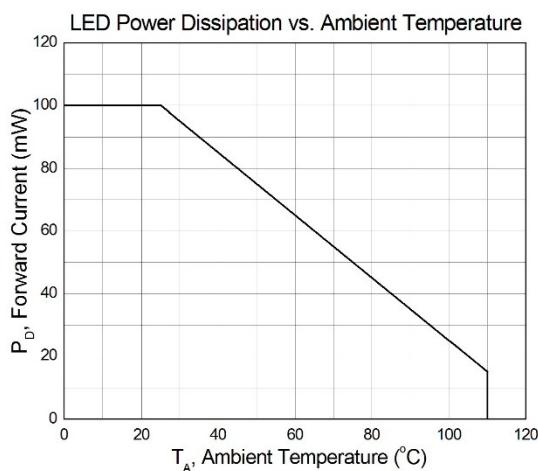


Figure 1

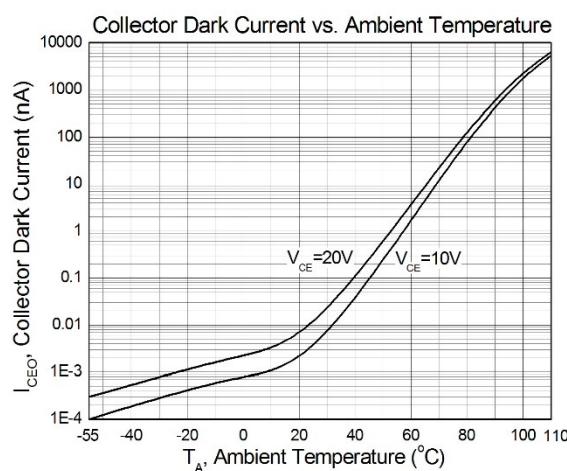


Figure 4

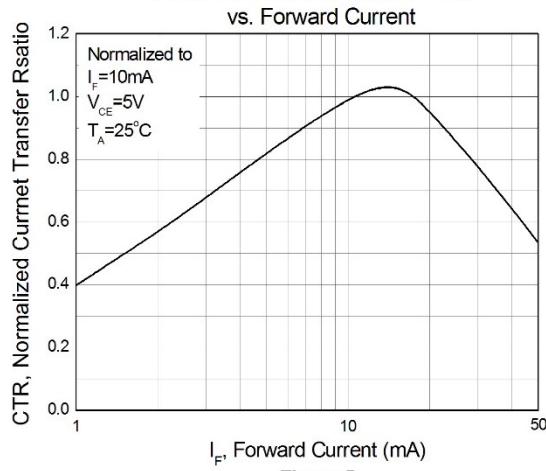


Figure 5

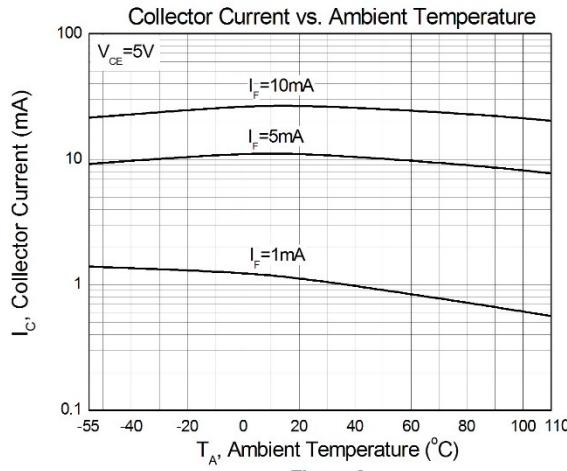
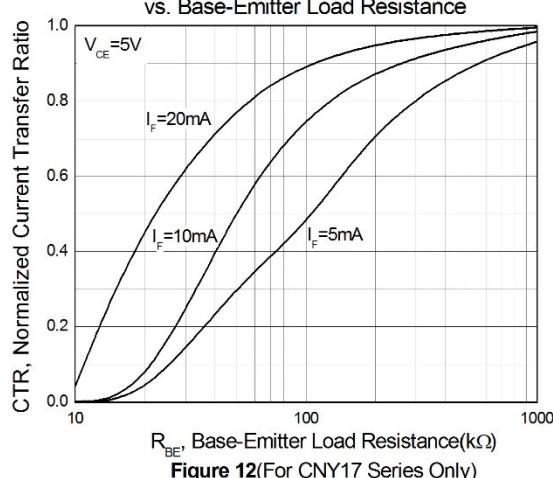
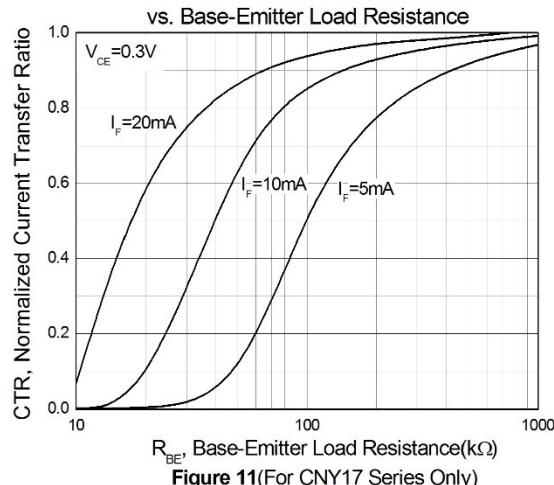
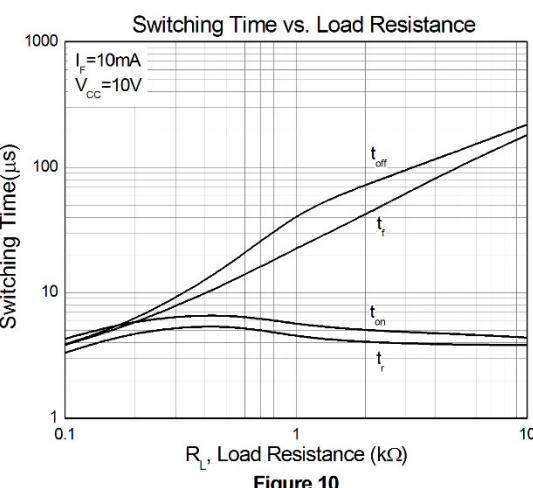
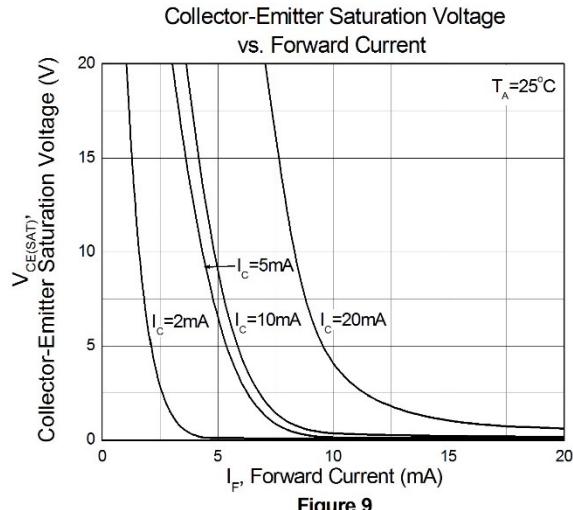
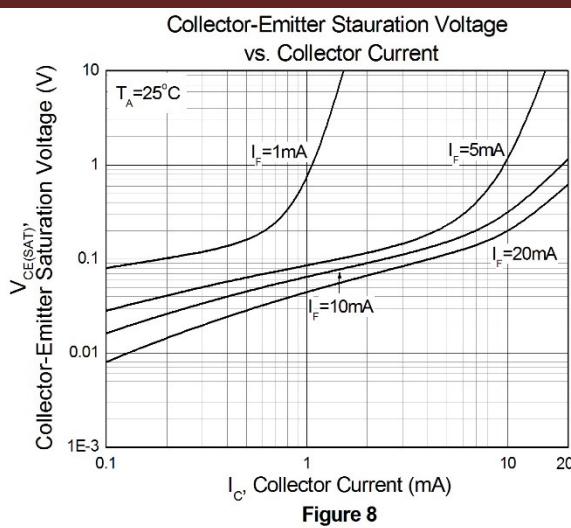
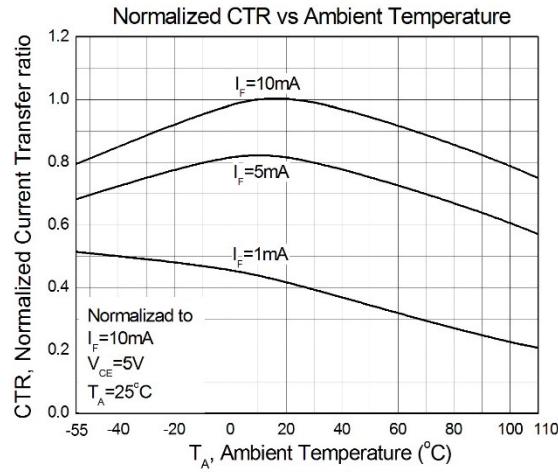


Figure 6

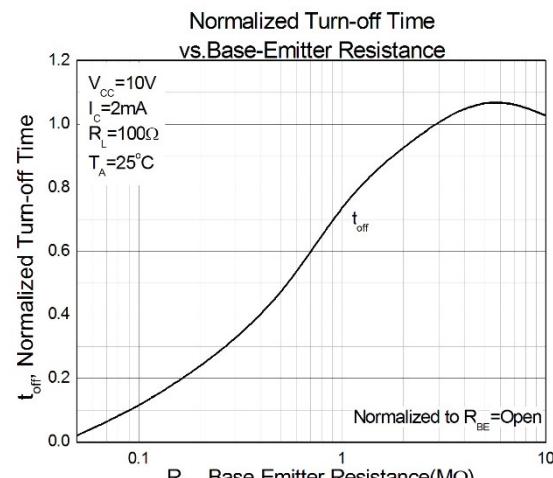
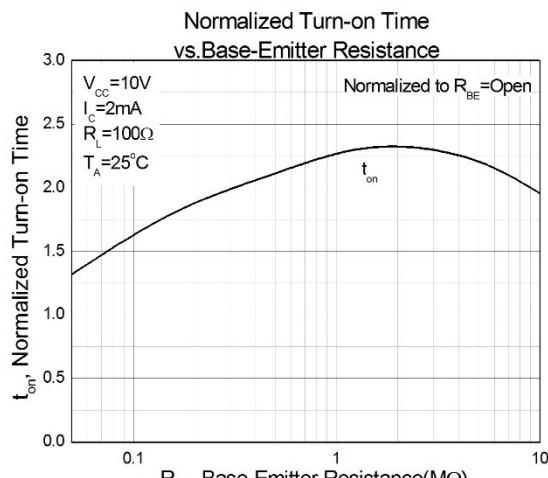


CNY17-1, CNY17-2, CNY17-3, CNY17-4 CNY17F-1, CNY17F-2, CNY17F-3, CNY17F-4 DC Input 6-Pin Phototransistor Optocoupler





CNY17-1, CNY17-2, CNY17-3, CNY17-4 CNY17F-1, CNY17F-2, CNY17F-3, CNY17F-4 DC Input 6-Pin Phototransistor Optocoupler

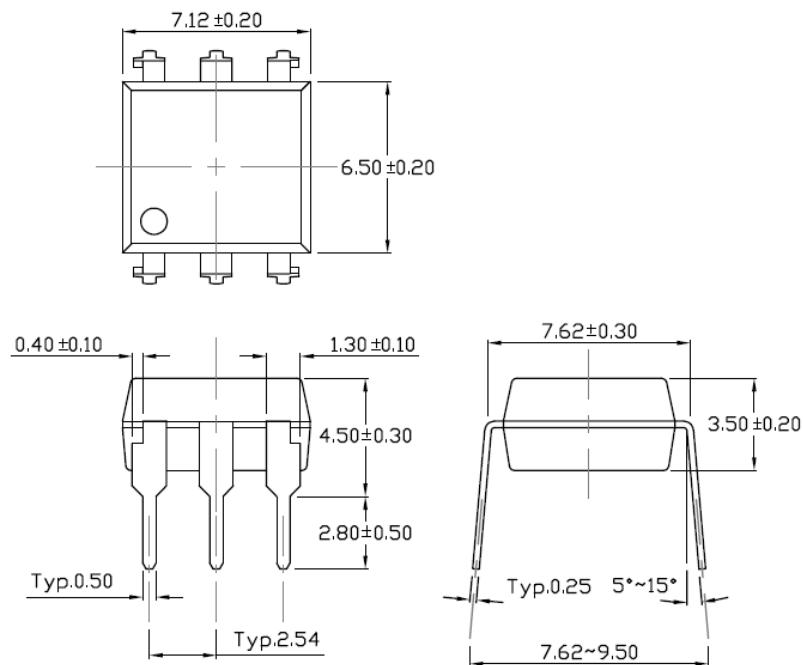




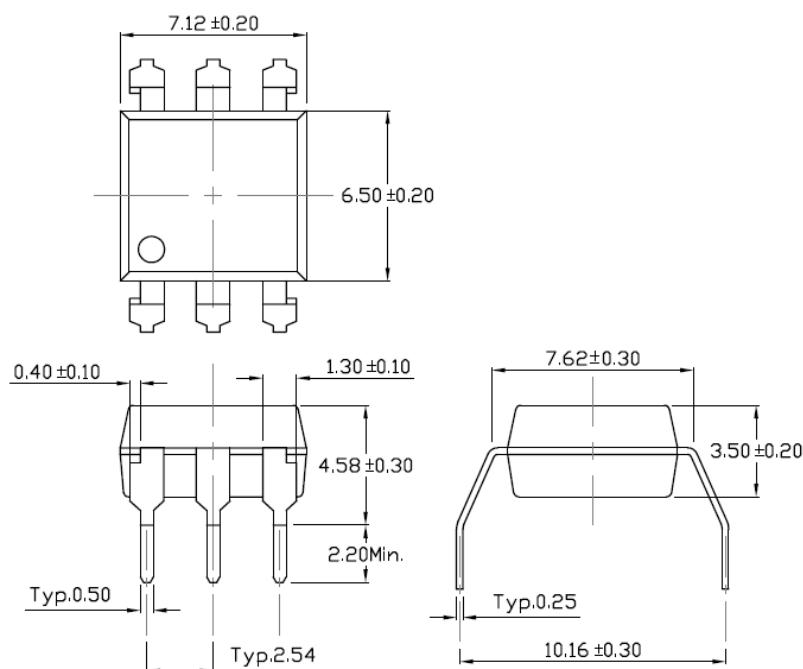
**CNY17-1, CNY17-2, CNY17-3, CNY17-4
CNY17F-1, CNY17F-2, CNY17F-3, CNY17F-4
DC Input 6-Pin Phototransistor Optocoupler**

Package Dimension *Dimensions in mm unless otherwise stated*

Standard DIP – Through Hole



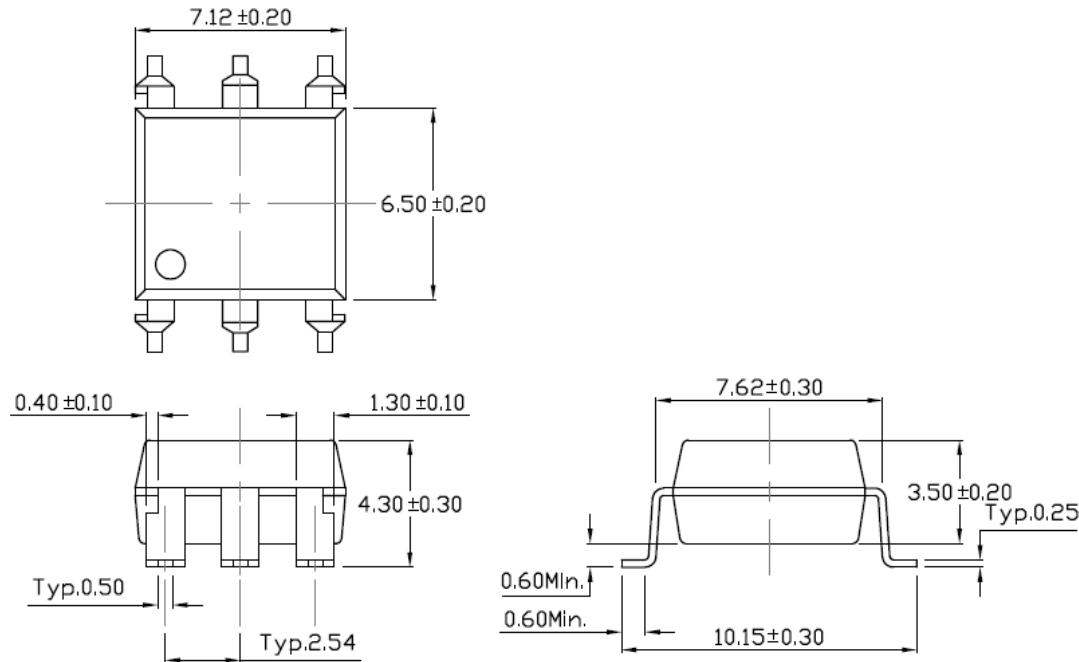
Wide Lead Forming – Through Hole (M Type)



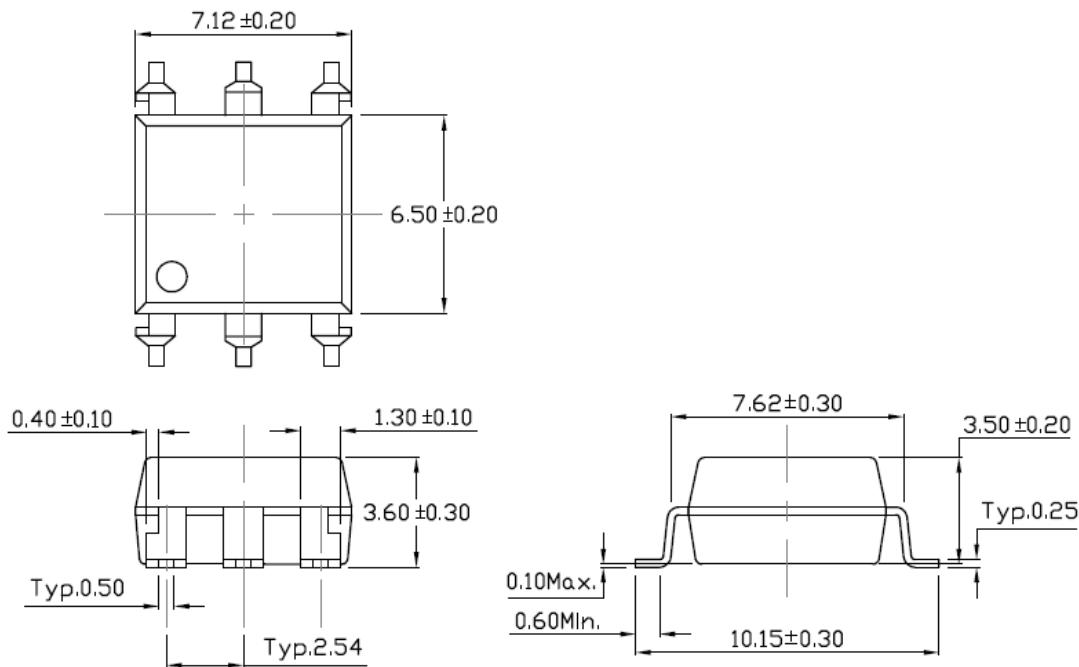


**CNY17-1, CNY17-2, CNY17-3, CNY17-4
CNY17F-1, CNY17F-2, CNY17F-3, CNY17F-4
DC Input 6-Pin Phototransistor Optocoupler**

Surface Mount Forming (S Type)



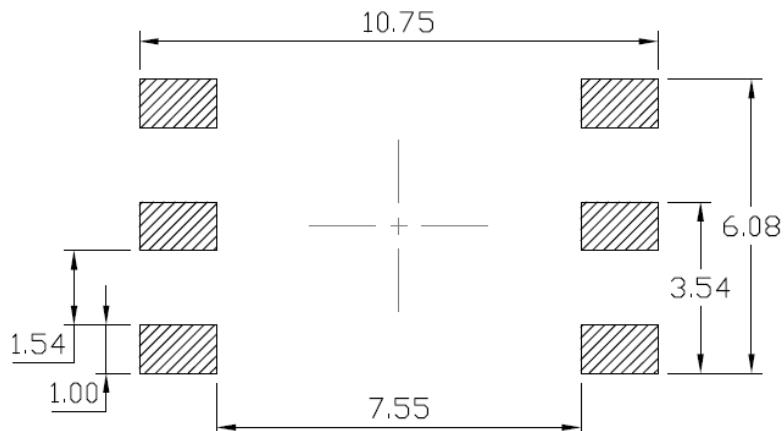
Surface Mount Forming (Low Profile) (SL Type)



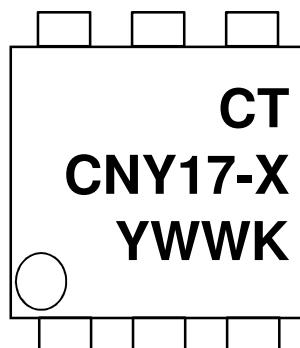


**CNY17-1, CNY17-2, CNY17-3, CNY17-4
CNY17F-1, CNY17F-2, CNY17F-3, CNY17F-4
DC Input 6-Pin Phototransistor Optocoupler**

Recommended Solder Mask Dimensions in mm unless otherwise stated



Marking Information



Note:

- CT : Denotes "CT Micro"
- CNY17-X : Part Number
- Y : Fiscal Year
- WW : Work Week
- K : Manufacturing Code



**CNY17-1, CNY17-2, CNY17-3, CNY17-4
CNY17F-1, CNY17F-2, CNY17F-3, CNY17F-4
DC Input 6-Pin Phototransistor Optocoupler**

Ordering Information

CNY17-X(Y)(Z)-G, CNY17F-X(Y)(Z)-G

X = Part No. (1,2,3,4)

Y = Lead form option (S, SL, M or none)

Z = Tape and reel option (T1, T2 or none)

G= Material option (G: Green, None: Non-green)

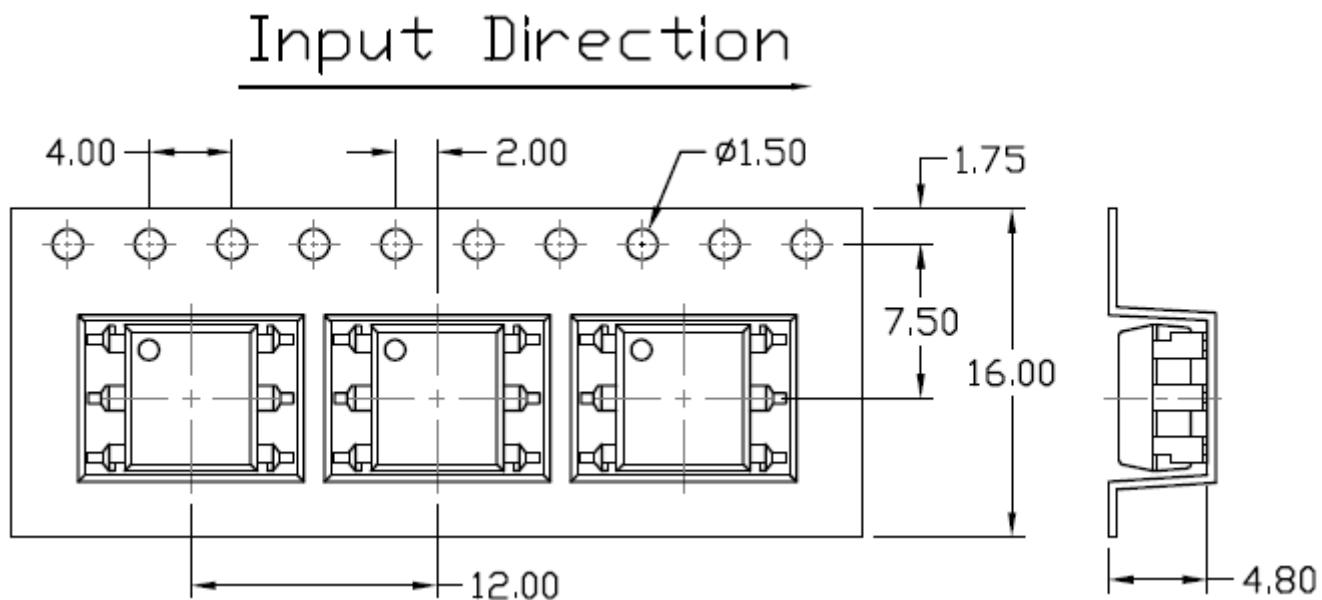
Option	Description	Quantity
None	Standard 6 Pin Dip	65Units/Tube
M	Gullwing (400mil) Lead Forming	65Units/Tube
S(T1)	Surface Mount Lead Forming – With Option 1 Taping	1000 Units/Reel
S(T2)	Surface Mount Lead Forming – With Option 2 Taping	1000 Units/Reel
SL(T1)	Surface Mount (Low Profile) Lead Forming– With Option 1 Taping	1000 Units/Reel
SL(T2)	Surface Mount (Low Profile) Lead Forming – With Option 2 Taping	1000 Units/Reel



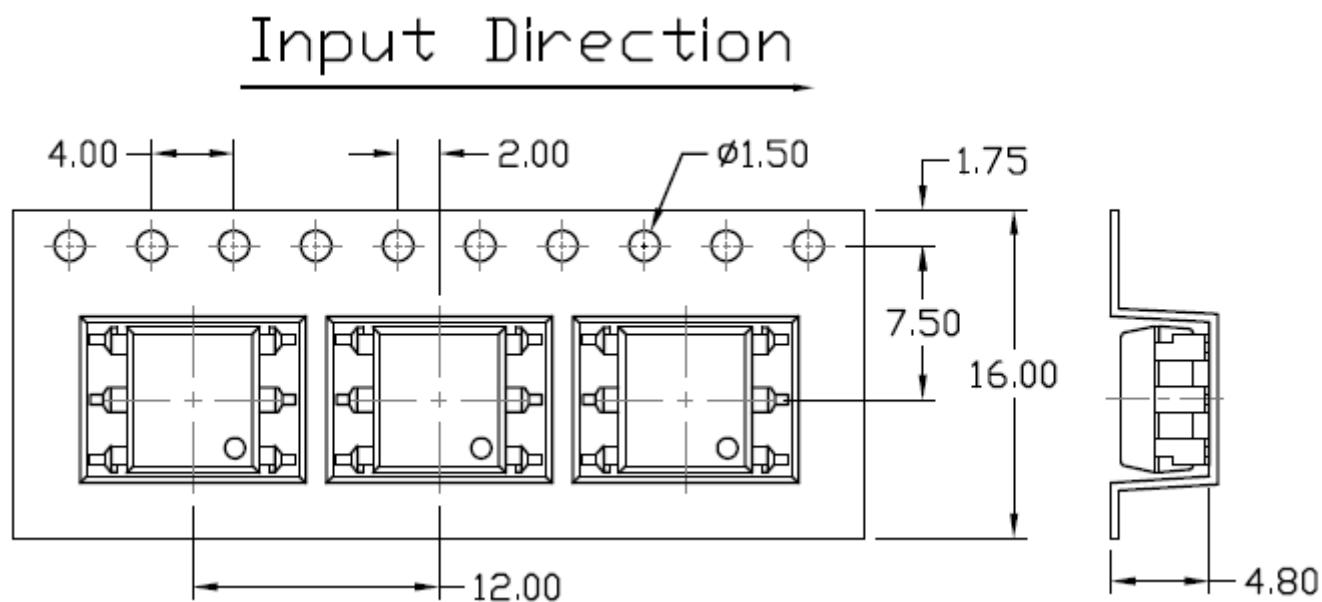
**CNY17-1, CNY17-2, CNY17-3, CNY17-4
CNY17F-1, CNY17F-2, CNY17F-3, CNY17F-4
DC Input 6-Pin Phototransistor Optocoupler**

Carrier Tape Specifications Dimensions in mm unless otherwise stated

Option S(T1) & SL(T1)



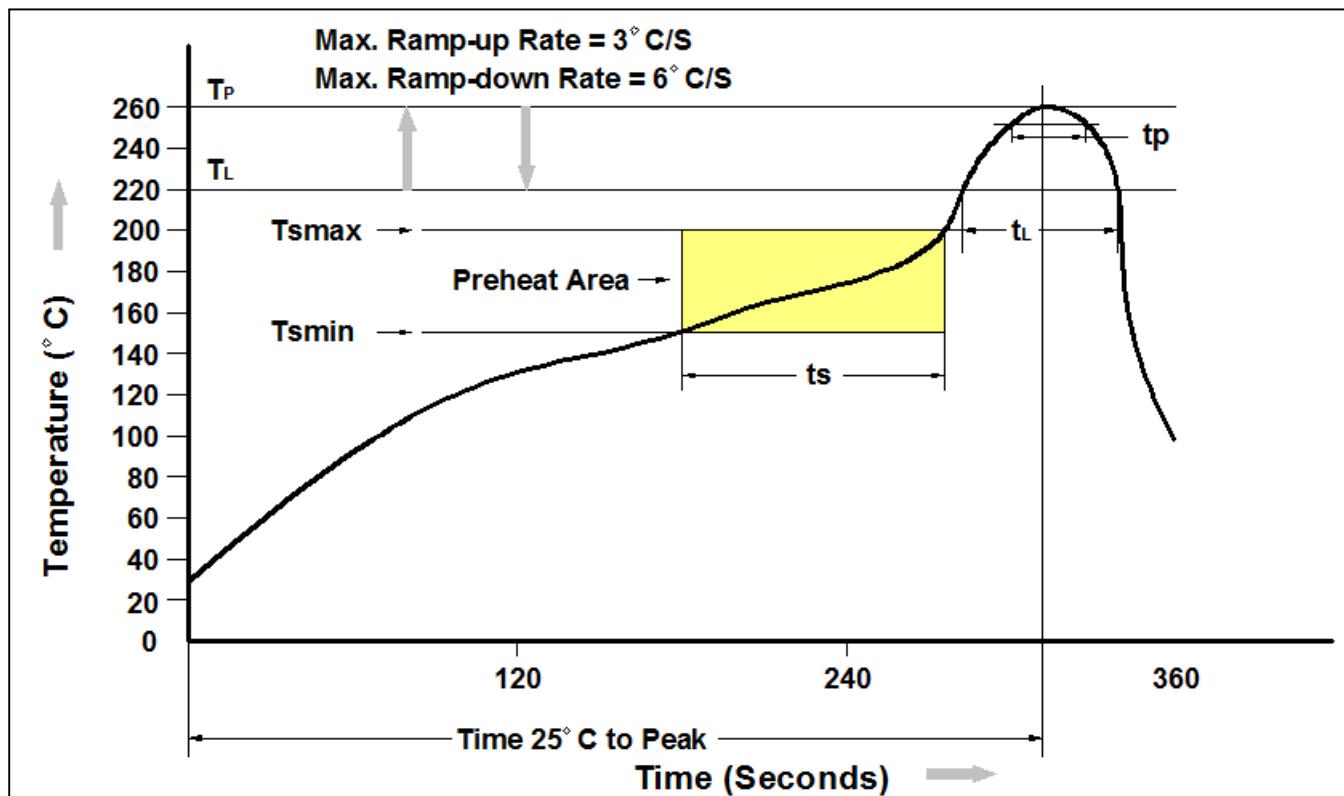
Option S(T2) & SL(T2)





**CNY17-1, CNY17-2, CNY17-3, CNY17-4
CNY17F-1, CNY17F-2, CNY17F-3, CNY17F-4
DC Input 6-Pin Phototransistor Optocoupler**

Reflow Profile



Profile Feature	Pb-Free Assembly Profile
Temperature Min. (T _{smin})	150°C
Temperature Max. (T _{smax})	200°C
Time (t _s) from (T _{smin} to T _{smax})	60-120 seconds
Ramp-up Rate (t _L to t _P)	3°C/second max.
Liquidous Temperature (T _L)	217°C
Time (t _L) Maintained Above (T _L)	60 – 150 seconds
Peak Body Package Temperature	260°C +0°C / -5°C
Time (t _P) within 5°C of 260°C	30 seconds
Ramp-down Rate (T _P to T _L)	6°C/second max
Time 25°C to Peak Temperature	8 minutes max.



**CNY17-1, CNY17-2, CNY17-3, CNY17-4
CNY17F-1, CNY17F-2, CNY17F-3, CNY17F-4
DC Input 6-Pin Phototransistor Optocoupler**

DISCLAIMER

CT MICRO RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. CT MICRO DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

DISCOLORATION MIGHT OCCUR ON THE PACKAGE SURFACE AFTER SOLDERING, REFLOW OR LONG TERM USE. THIS DOES NOT IMPACT THE PRODUCT PERFORMANCE NOR THE PRODUCT RELIABILITY.

CT MICRO ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT EXPRESS WRITTEN APPROVAL OF CT MICRO INTERNATIONAL CORPORATION.

1. *Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instruction for use provided in the labelling, can be reasonably expected to result in significant injury to the user.*
2. *A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.*